

NPN SILICON GERMANIUM RF TRANSISTOR NESG3031M14

NPN SIGE RF TRANSISTOR FOR LOW NOISE, HIGH-GAIN AMPLIFICATION 4-PIN LEAD-LESS MINIMOLD (M14, 1208 PKG)

FEATURES

- The device is an ideal choice for low noise, high-gain amplification NF = 0.6 dB TYP., G_a = 16.0 dB TYP. @ VcE = 2 V, Ic = 6 mA, f = 2.4 GHz NF = 0.95 dB TYP., G_a = 10.0 dB TYP. @ VcE = 2 V, Ic = 6 mA, f = 5.2 GHz
 - NF = 0.95 dB TYP., $G_a = 10.0$ dB TYP. @ VCE = 2 V, IC = 6 mA, f = 5.2 GHz NF = 1.1 dB TYP., $G_a = 9.5$ dB TYP. @ VCE = 2 V, Ic = 6 mA, f = 5.8 GHz
- Maximum stable power gain: MSG = 15.0 dB TYP. @ VcE = 3 V, Ic = 20 mA, f = 5.8 GHz
- SiGe HBT technology (UHS3) adopted: fmax = 110 GHz
- 4-pin lead-less minimold (M14, 1208 PKG)

<R> ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG3031M14	NESG3031M14-A	4-pin lead-less minimold	50 pcs (Non reel)	• 8 mm wide embossed taping
NESG3031M14-T3	NESG3031M14-T3-A	(M14, 1208 PKG) (Pb-Free)	10 kpcs/reel	• Pin 1 (Collector), Pin 4 (Emitter) face the perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office. Unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS ($T_A = +25$ °C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	Vсво	12.0	V
Collector to Emitter Voltage	Vceo	4.3	V
Emitter to Base Voltage	VEBO	1.5	V
Collector Current	lc	35	mA
Total Power Dissipation	P _{tot} Note	150	mW
Junction Temperature	Tj	150	°C
Storage Temperature	T _{stg}	-65 to +150	°C

Note Mounted on 1.08 cm² × 1.0 mm (t) glass epoxy PWB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	Ісво	VcB = 5 V, IE = 0 mA	-	-	100	nA
Emitter Cut-off Current	Ієво	V _{EB} = 1 V, I _C = 0 mA	-	-	100	nA
DC Current Gain	hfe Note 1	VcE = 2 V, Ic = 6 mA	220	300	380	ı
RF Characteristics						
Insertion Power Gain	S _{21e} ²	VcE = 3 V, Ic = 20 mA, f = 5.8 GHz	6.5	9.0	-	dB
Noise Figure (1)	NF	$\label{eq:Vce} \begin{array}{l} V_{\text{CE}} = 2 \; V, \; I_{\text{C}} = 6 \; \text{mA}, \; f = 2.4 \; \text{GHz}, \\ Z_{\text{S}} = Z_{\text{Sopt}}, \; Z_{\text{L}} = Z_{\text{Lopt}} \end{array}$	-	0.6	-	dB
Noise Figure (2)	NF	$\label{eq:Vce} \begin{array}{l} V_{\text{CE}} = 2 \; V, \; I_{\text{C}} = 6 \; \text{mA}, \; f = 5.2 \; \text{GHz}, \\ Z_{\text{S}} = Z_{\text{Sopt}}, \; Z_{\text{L}} = Z_{\text{Lopt}} \end{array}$	-	0.95	-	dB
Noise Figure (3)	NF	$\label{eq:Vce} \begin{array}{l} V_{\text{CE}} = 2 \; V, \; I_{\text{C}} = 6 \; \text{mA}, \; f = 5.8 \; \text{GHz}, \\ Z_{\text{S}} = Z_{\text{Sopt}}, \; Z_{\text{L}} = Z_{\text{Lopt}} \end{array}$	-	1.1	1.5	dB
Associated Gain (1)	Ga	$V_{CE} = 2 \text{ V}, \text{ Ic} = 6 \text{ mA}, \text{ f} = 2.4 \text{ GHz}, $ $Z_S = Z_{Sopt}, Z_L = Z_{Lopt}$	-	16.0	-	dB
Associated Gain (2)	Ga	$V_{CE} = 2 \text{ V, Ic} = 6 \text{ mA, f} = 5.2 \text{ GHz,}$ $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	-	10.0	-	dB
Associated Gain (3)	Ga	$\label{eq:Vce} \begin{split} &V_{\text{CE}} = 2 \text{ V, Ic} = 6 \text{ mA, f} = 5.8 \text{ GHz,} \\ &Z_{\text{S}} = Z_{\text{Sopt, ZL}} = Z_{\text{Lopt}} \end{split}$	7.5	9.5	-	dB
Reverse Transfer Capacitance	Cre Note 2	VcB = 2 V, IE = 0 mA, f = 1 MHz	-	0.15	0.25	pF
Maximum Stable Power Gain	MSG ^{Note}	VcE = 3 V, Ic = 20 mA, f = 5.8 GHz	12.0	15.0	-	dB
Gain 1 dB Compression Output Power	Po (1 dB)	$\begin{aligned} &\text{Vce} = 3 \text{ V, Ic (set)} = 20 \text{ mA,} \\ &\text{f} = 5.8 \text{ GHz, Zs} = Z_{\text{Sopt, ZL}} = Z_{\text{Lopt}} \end{aligned}$	-	13.0	_	dBm
Output 3rd Order Intercept Point	OIP ₃	$\begin{split} \text{V}_{\text{CE}} &= 3 \text{ V, Ic (set)} = 20 \text{ mA,} \\ f &= 5.8 \text{ GHz, Zs} = Z_{\text{Sopt, ZL}} = Z_{\text{Lopt}} \end{split}$	-	18.0	-	dBm

Notes 1. Pulse measurement: PW \leq 350 μ s, Duty Cycle \leq 2%

2. Collector to base capacitance when the emitter grounded

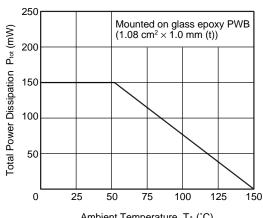
3. MSG =
$$\frac{S_{21}}{S_{12}}$$

hfe CLASSIFICATION

Rank	FB		
Marking	zJ		
h _{FE} Value	220 to 380		

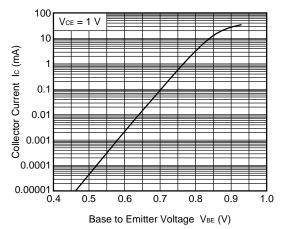
TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

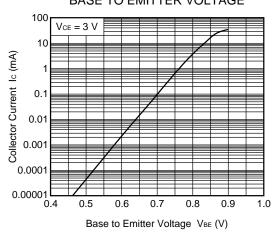


Ambient Temperature T_A (°C)

COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

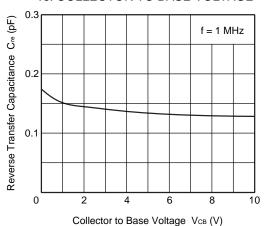


COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

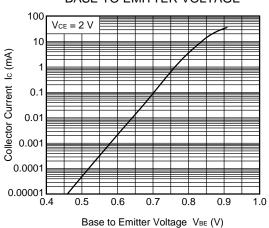


Remark The graphs indicate nominal characteristics.

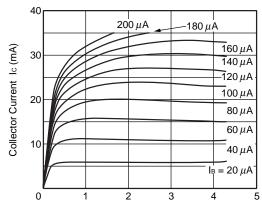
REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

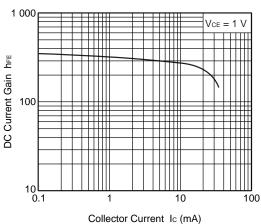


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

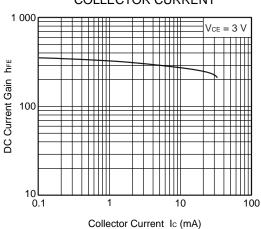


Collector to Emitter Voltage VcE (V)

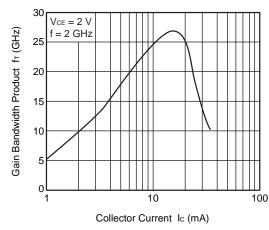




DC CURRENT GAIN vs. **COLLECTOR CURRENT**

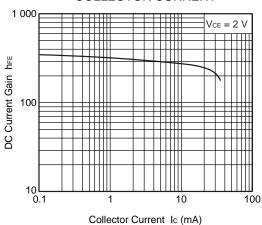


GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

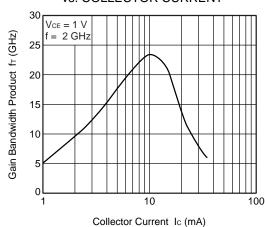


Remark The graphs indicate nominal characteristics.

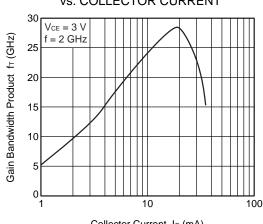
DC CURRENT GAIN vs. COLLECTOR CURRENT



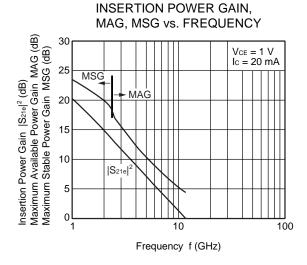
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

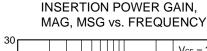


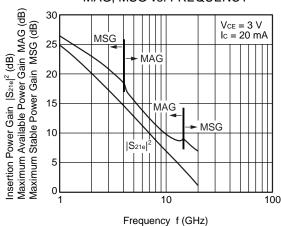
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



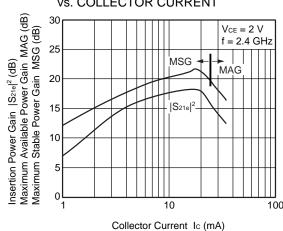
Collector Current Ic (mA)





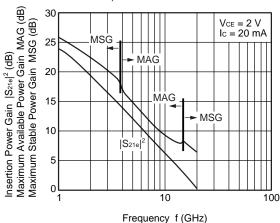


INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

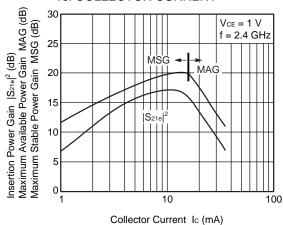


Remark The graphs indicate nominal characteristics.

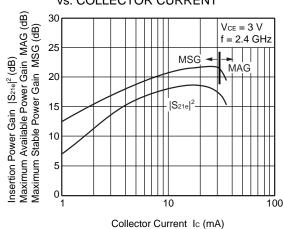
INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



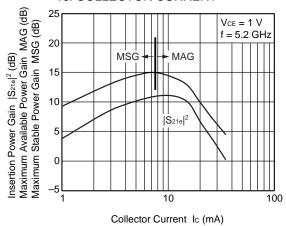
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



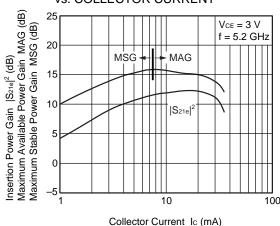
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



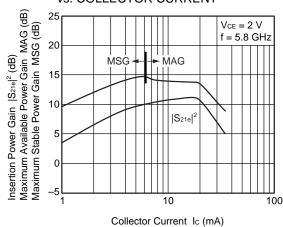
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

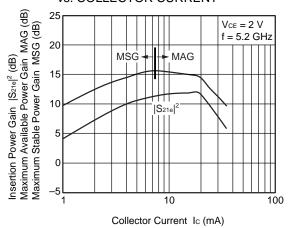


INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

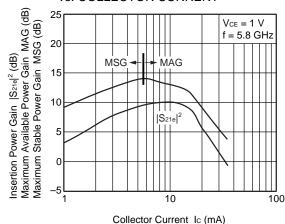


Remark The graphs indicate nominal characteristics.

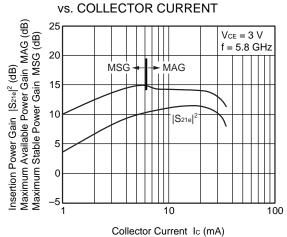
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



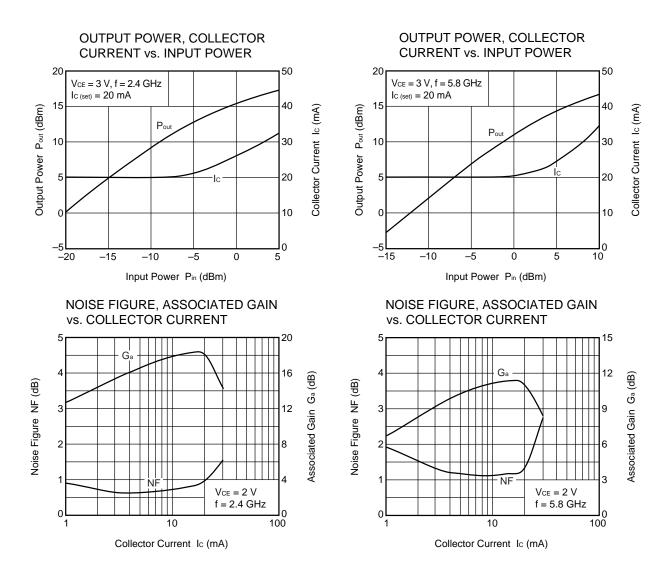
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



INSERTION POWER GAIN, MAG, MSG



6



Remark The graphs indicate nominal characteristics.

<R> S-PARAMETERS

S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.

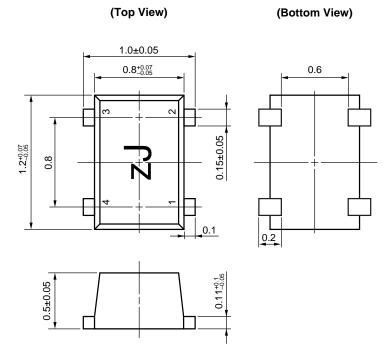
Click here to download S-parameters.

[RF and Microwave] \rightarrow [Device Parameters]

URL http://www.necel.com/microwave/en/

<R> PACKAGE DIMENSIONS

4-PIN LEAD-LESS MINIMOLD (M14, 1208 PKG) (UNIT: mm)



PIN CONNECTIONS

- 1. Collector
- 2. Emitter
- 3. Base
- 4. Emitter

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